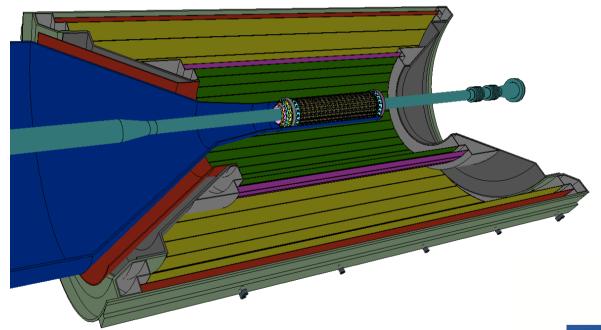


The ALICE Inner Tracker Upgrade



Petra Riedler/CERN on behalf of the ALICE ITS upgrade collaboration





Outlook

- The ALICE upgrade strategy
- The upgrade of the ALICE Inner Tracker
 - Present system
 - Upgrade plans: motivation, design goals, requirements
- R&D activities status and outlook
 - Pixel technologies: monolithic hybrid
 - System layout considerations
 - Interconnection and bus studies
- Summary

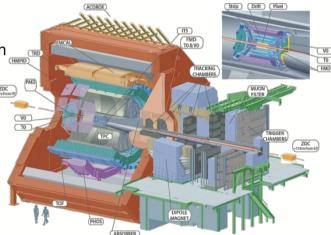


The ALICE upgrade

ALICE – dedicated heavy ion experiment to study strongly interacting matter at extreme energy densities

The upgrade targets physics topics uniquely accessible to ALICE:

- Measurement of heavy-flavour transport parameters:
 - diffusion coefficient azimuthal anisotropy and R_{AA}
 - in-medium thermalization and hadronization meson-baryon mass dependence of energy loss – R_{ΔΔ}
 - study of QGP properties via transport coefficients (η/s, q)
- J/ ψ , ψ ', and χ_c states down to zero p_t in wide rapidity range
 - yields and transverse momentum spectra R_{AA}, elliptic flow
 - density dependence central vs. forward production
 - statistical hadronization vs. dissociation/recombination
- Measurement of low-mass and low-p, dileptons
 - chiral symmetry restoration vector-meson spectral function
 - (disappearance of vacuum condensate and generation of hadron masses)
 - QGP thermal radiation low-mass dilepton continuum
 - space-time evolution of the QGP radial and elliptic flow of emitted radiation

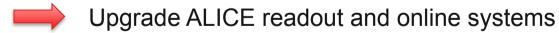




The ALICE upgrade

High precision measurements of rare probes at low p_T after the long shutdown at 2018/19, which cannot be selected with a trigger, require a large sample of events recorded on tape and **improvement on vertexing and tracking** capabilities.

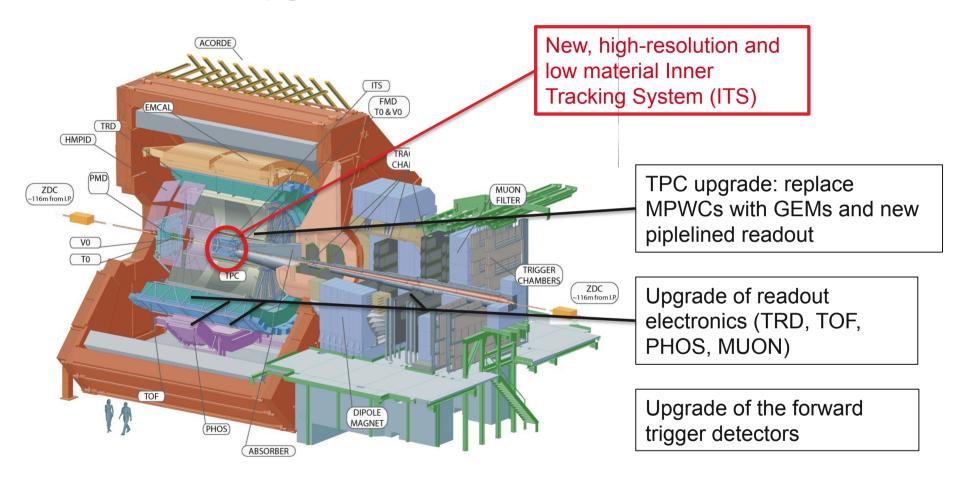
Pb-Pb recorded luminosity	≥ 10 nb ⁻¹	8 x 10 ¹⁰ events
pp (@5.5 Tev) recorded luminosity	≥ 6 pb ⁻¹	1.4 x 10 ¹¹ events







The ALICE upgrade

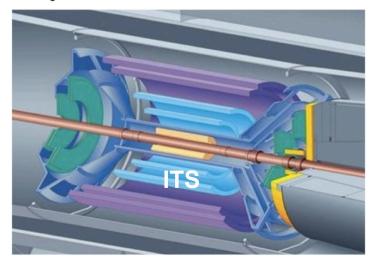


Upgrade of online systems and of offline reconstruction and analysis framework and code



The present ITS

- 6 layers of silicon detectors (pixels, drift, strips)
- PID (drift and strips)
- Pixel multiplicity trigger
- Low material budget: 1.14 % X₀ per pixel layer, 7.2 % X₀ for ITS
- L₀ at 3.9 cm from IP



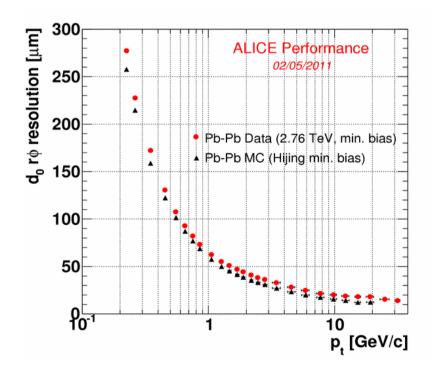






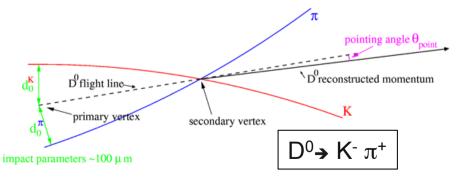
The present ITS

Impact parameter resolution



Limitations:

- Charmed mesons difficult for p_T→0 (background is too large)
- resolution not sufficient for charmed baryons, Λ_c (c τ ~60 μ m) impossible in Pb-Pb collisions , at the limit in pp (only high p_T)
- Λ_b impossible in Pb-Pb collisions (insufficient statistics and resolution)
- indirect B measurement via electrons, B/D separation difficult, especially at low p_t (e
 PID + vertexing)





Design goals

Improve impact parameter resolution by a factor of ~3 (r-phi)

- Get closer to IP
- Reduce material budget
- Reduce pixel size

High standalone tracking efficiency and pt resolution

- Increase granularity
- Increase radial extension

Fast readout

Readout of Pb-Pb interactions at 50 kHz

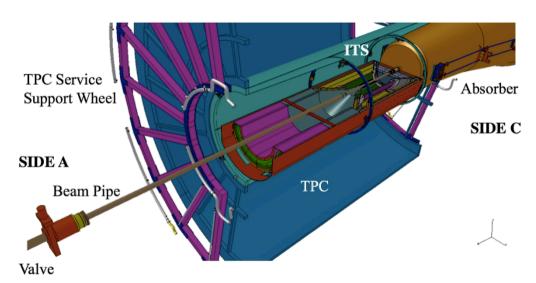
Fast insertion/removal for yearly maintenance

Possibility to replace non functioning detector modules during yearly winter shutdown



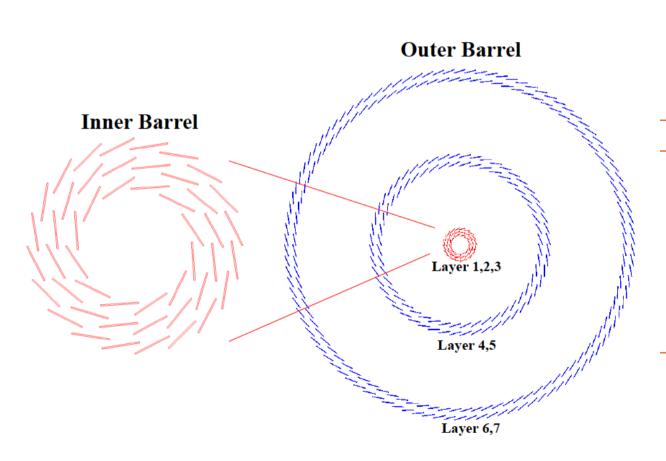
Tracker geometry - 1

- Beampipe outer radius: r=17.2 mm
 - presently 29.8 mm
- First layer at 22 mm
 - presently 39 mm
- Radial coverage up to 430 mm
- 7 layers
 - presently 6
- |η|<1.22 over 90% of the luminous region
 - presently 0.9





Tracker geometry - 2



Layer	Radius [cm]	+/- z
1	2.2	11.2
2	2.8	12.1
3	3.6	13.4
4	20	39.0
5	22	41.8
6	41	71.2
7	43	74.3



Requirements

Targets for Inner Layers (1, 2, 3)

Pixel size ($r\phi \times z$): 20 x 20 μ m²

 $(max: 30 \times 50 \mu m^2)$

Readout time: <30 μs

Chip size: 15 mm x 30 mm (target)

Material budget per layer: 0.3 % X₀

Radiation: 700 krad/ 10¹³ n_{eq}

Hit density: <150 cm⁻² in layer 1

Power Density: 0.3 W/cm²

(max: 0.5 W/cm²)

Targets for Outer Layers (4, 5, 6, 7)

Cell size (rφ x z): max: 70 μm x 2 cm

Readout time: <30 µs

Material budget per layer: 0.3 % X₀

(max: $0.8\% X_0$)

Radiation: 10 krad/ 3•10¹¹ n_{eq}

Hit density: 1 cm⁻² in layer 4

Power Density: 0.3 W/cm²

(max: 0.5 W/cm²)





Pixels or Strips



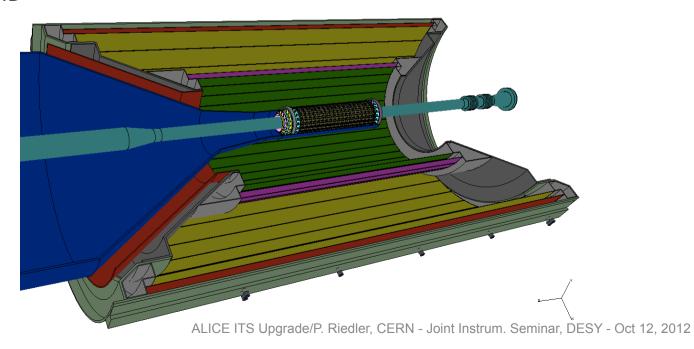
2 layout options

A. 7 layers of pixel detectors

better standalone tracking efficiency and p_t resolution

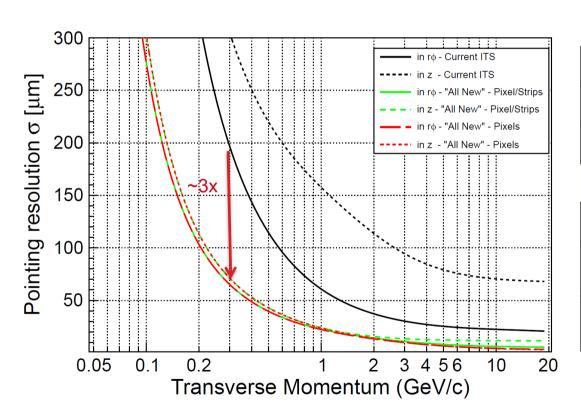
B. 3 inner layers of pixel detectors and 4 outer layers of strip detectors

- worse standalone tracking efficiency and momentum resolution
- PID





Performance - 1

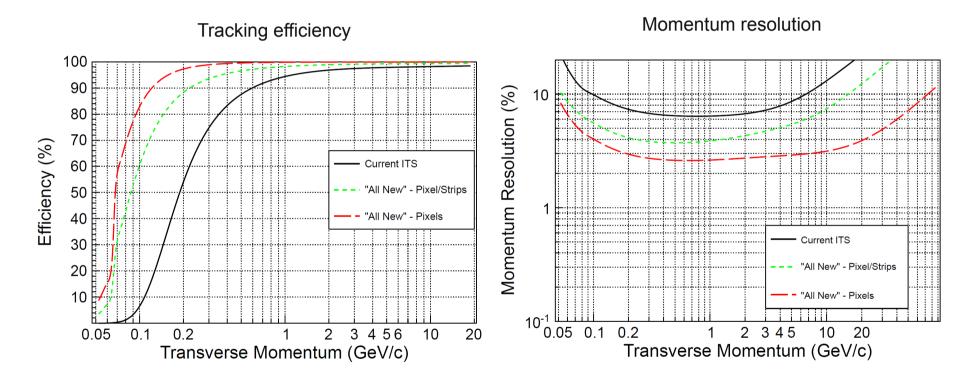


Layout A (7 pixel layers)			
$\sigma_{r\phi}$ = 4 µm	$σ_z$ =4 μm		
X/X ₀	0.3 %		

Layout B (3 pixel + 4 strip layers)			
$σ_{rφ}$ = 4 μm (pixel), 20 μm (strips)	$σ_z$ =4 μm (pixel), 830 μm (strips)		
X/X ₀	0.3% (pixel), 0.8 % (strips		



Performance - 1



Layout A (7 pixel layers)

Layout B (3 pixel + 4 strip layers)

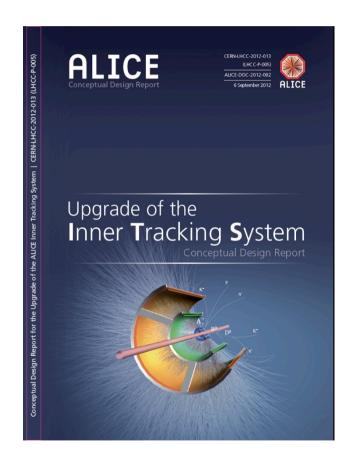


Conceptual Design Report

Presents physics case, detector performance studies and R&D on detector technologies, mechanics and cooling aspects.

Version CDR1 presented to LHCC in September 2012 (available on CDS).

http://cdsweb.cern.ch/record/1475244/files/LHCC-P-005.pdf





R & D activities

Focus is set on several key points, mainly related to pixels. The layout of the strips layers follows closely the present strip detector installed in ALICE.

R&D activities related to detector technology, mechanics and cooling in 2012 presented in the following slides:

- Silicon strip detector design
- Irradiation tests of 0.18 µm CMOS technology
- Development and test of prototype pixel matrices
- Thin hybrid pixel detectors
- Thinning tests to 50 µm
- Evaluation of interconnection techniques
- First studies of module concepts
- Mechanical concept and cooling studies



Silicon Strip R&D

Sensor design based on current ALICE SSD

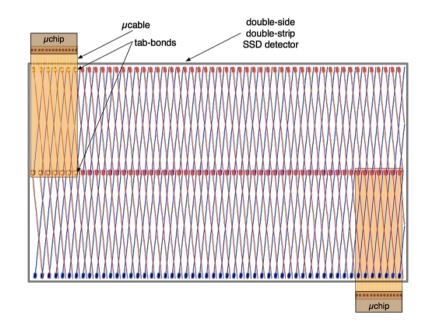
- Standard 300 μm double-sided micro-strip sensors
- 768 strip/side, 35 mrad stereo angle

Reduced strip length down to 20 mm

- Half cell-size: 95 μm x 20 mm
 - Higher granularity
 - Better ghost hit rejection
- Doubled channel density
 - Challenging interconnection layout
 - Power consumption

New ASIC design:

- 0.18 μm technology (rad. hard)
- Low power and fast ADC (10 bits)
- Preserve 20 MIP range and 0.1 MIP resolution





Pixel technologies

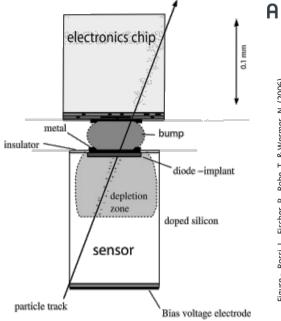
2 basic concepts

Hybrid pixels

- Separate optimization of sensor and circuitry, complex in-pixel signal processing
- State-of-the-art detectors but are limited to inner layers due to their cost
- Charge collected by drift, high resistivity wafers (4-6 kΩcm)
- Proven radiation resistance to ALICE levels

Monolithic pixels

- Sensing layer (~1kOhmcm) is integrated into the CMOS chip
- Have shown significant progress in recent years and will soon be installed in STAR (HFT)
- Charge collected by drift and diffusion
- Thickness of the sensing layer typically 10-20 μm
- Radiation resistance needs to be proven



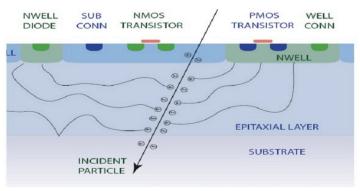


Figure Stanitzki, M. (2010). Nucl. Instr. and Meth. A doi:10.1016/j.nima.2010.11.166

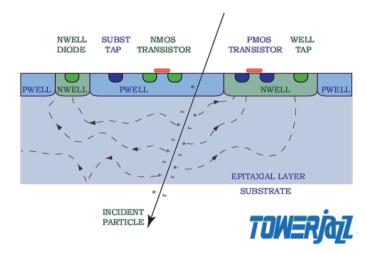


CMOS

New specialty CMOS technologies available for monolithic pixel detectors.

Development of monolithic detectors using Tower/Jazz 0.18 µm CMOS technology:

- Improved TID resistance due to smaller technology node
- Available with high resistivity (1-5k Ω•cm) epitaxial layer up to 18 μm (substantial depletion at 1-2V)
- Special quadruple-well available to shield PMOS transistors (allows in-pixel truly CMOS circuitry)



CMOS with deep p-well

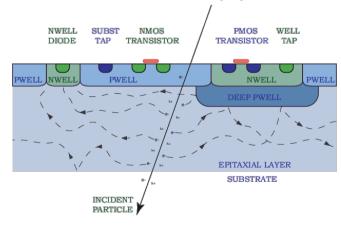


Figure Stanitzki, M. (2010). Nucl. Instr. and Meth. A doi:10.1016/j.nima.2010.11.166



Radiation hardness tests of structures in 0.18 µm

- 1. Test of basic structures (transistors, shift registers etc.)
 - Study threshold shift, leakage current, SEU, ...
- 2. Test of prototype matrices
 - Study of charge collection performance, noise, ...



Transistors, capacitors, diodes,...

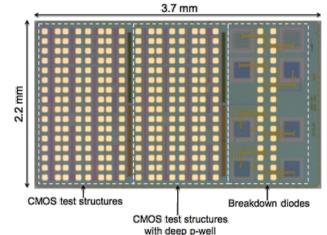


Prototype matrices



Transistor structures in 0.18 µm

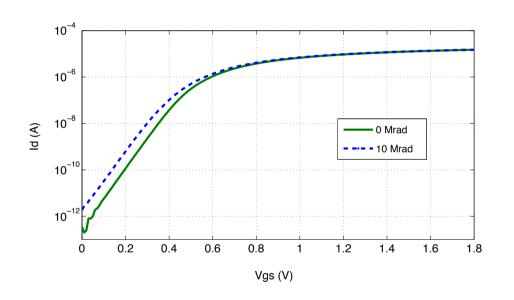
- Designed in 2012 containing single NMOS and PMOS transistors (w/wo deep-p-well) and breakdown structures (CERN).
- First structures irradiated at the X-ray system at CERN in summer 2012 up to 10 Mrad.
- Following standardized irradiation procedure with annealing of 24 hours and 1 week.
- During irradiation worst case bias scenario
 (V_a = 1.8 V, V_s = 0 V, V_d = 0 V, V_{sub} = 0 V)

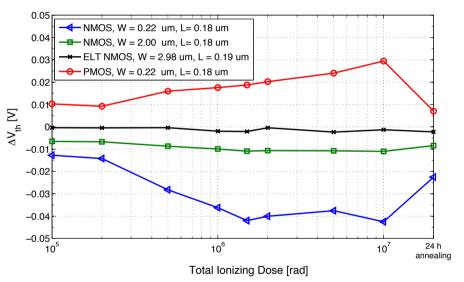






Transistor structures in 0.18 µm – first results





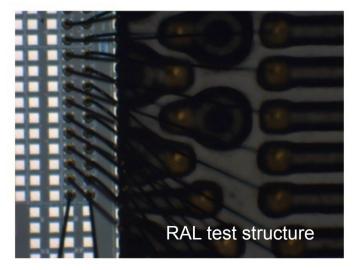
Drain current as function of the gate voltage Minimum size NMOS

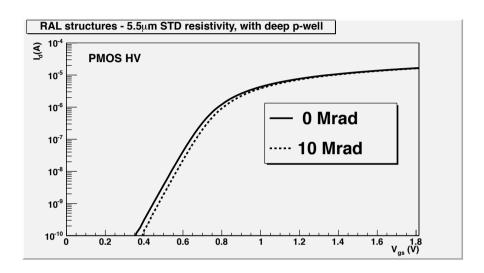
Threshold shift as function of TID

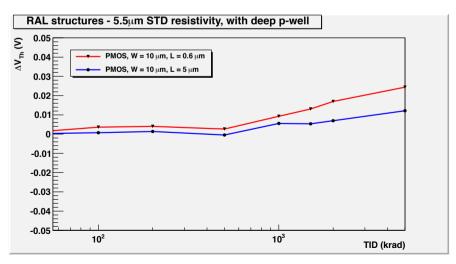


Transistor structures in 0.18 µm

- Test structures designed by RAL with single transistors, capacitors and insulations structures were available for tests.
- First results from X-ray irradiation tests carried out with test system developed at CERN.



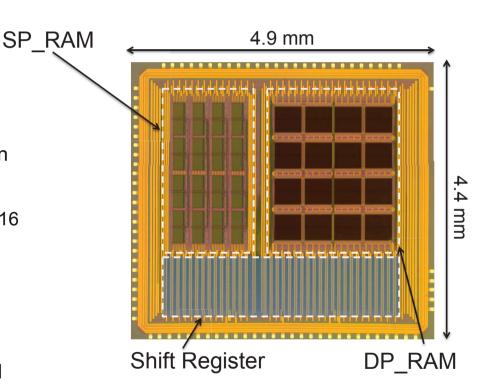






SEU chip

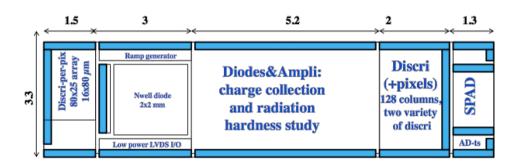
- Dedicated structure designed to study the Single Event Upset (SEU) sensitivity of the 0.18µm CMOS technology (CERN, CCNU).
- Contains 3 modules which share a common clock (10 MHz) and I/Os:
 - 16 single port RAM memories of 1024x16 bits
 - 8 dual port RAM memories of 2048x16 bits
 - 16 bit 2048 stages shift register
- The test system is currently being completed and first tests are planned for the end of October

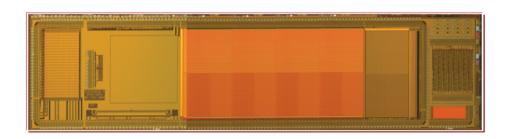




MIMOSA32

- Designed by IPHC Strasbourg
- Digital and analog blocks (2T and 3T structures with various diodes)
- Test with Fe⁵⁵ source
- Irradiation tests (X-ray, neutron)
- Beam-tests Jun, Jul and Aug 2012 at CERN

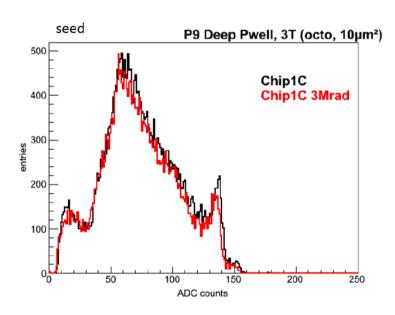


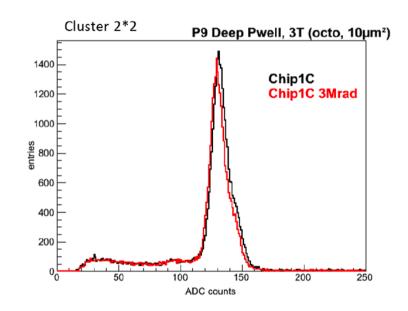




MIMOSA32

Measurement with Fe⁵⁵ source before and after X-ray irradiation





Charge collected in seed pixel Collects typically 40-50%

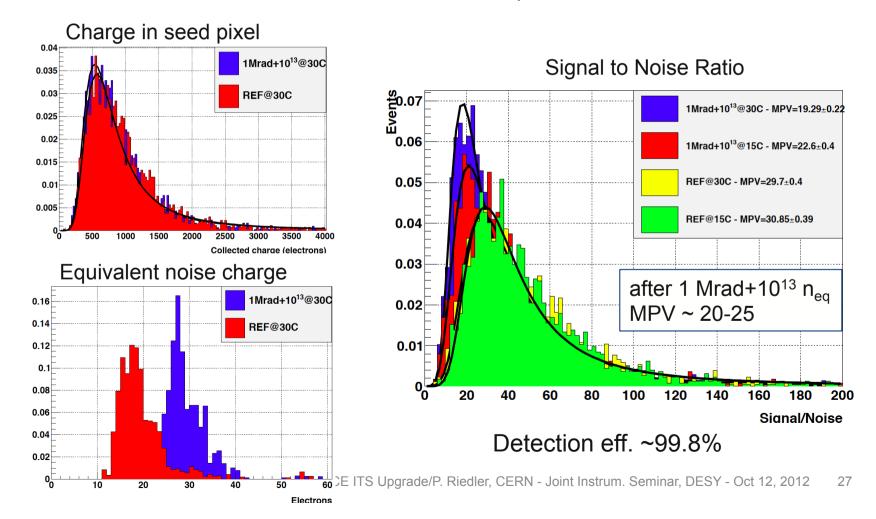
Cluster signal of cluster size 2x2

Pixel noise 15-20 electrons at RT (20°C)



MIMOSA32

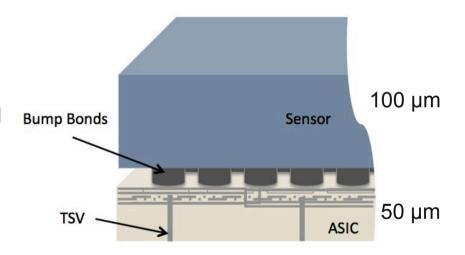
Measurements at SPS test beam with 60-120 GeV particles





Hybrid pixel R&D for the ALICE ITS

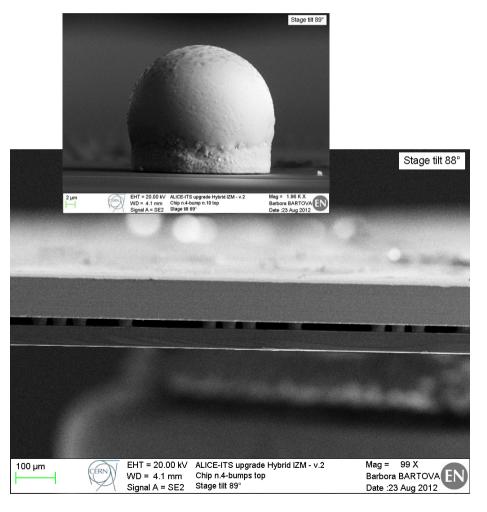
- Development with IZM Berlin to produce hybrid pixel detector with 50 µm chip and 100 µm sensor
 - Tests with dummy components using ALICE SPD layout
 - Ladders (5 chips + 1 sensor) and singles with final thicknesses bonded and delivered
- Participate in TSV studies with Medipix
- Study of edgeless sensors:
 - Using epitaxial and standard FZ wafers (FBK and VTT)

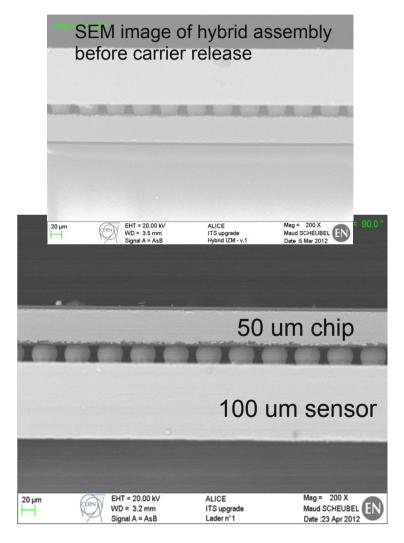




Hybrid pixel R&D for the ALICE ITS

Thin dummy assemblies - IZM







Thinning tests

CMOS wafers

Work with commercial supplier to **thin wafers to 50 µm** assuming chip size of 15 mm x 30 mm

- Thinning and dicing of blank 200 mm wafers
 (13) completed
- Thinning and dicing of patterned 200 mm wafers (pads for interconnection tests) 5 wafers completed
- Thinning and dicing of one MIMOSA20 wafer
 (die size 10 mm x 20 mm) completed

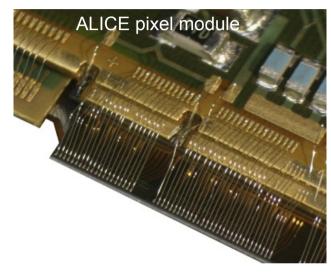


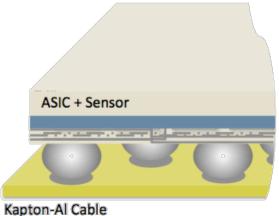


Interconnection studies

Techniques

- Wedge wire bonding is the state of the art technique to connect silicon chips/sensors to a cable or printed circuit board.
- This implies a dedicated region on the ASIC for the wire bonding pads and end of column circuitry. This area is not sensitive to passing particles and adds to the dead area.
- Wire bonding is one option for interconnection, but alternatives are under investigation which allow a compact module design and a reduction of the insensitive area.

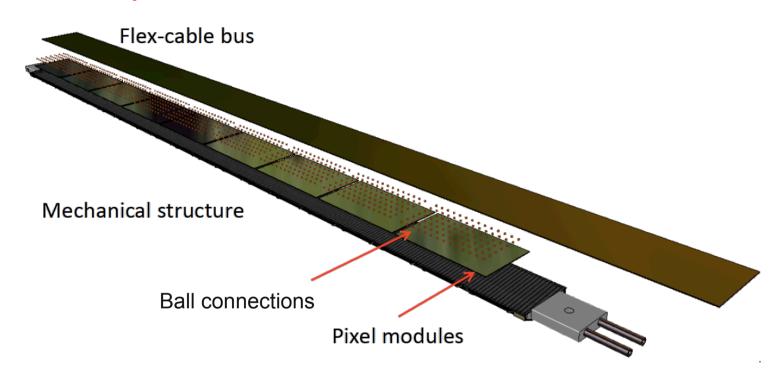






Interconnection studies and module concepts

Module concept



Study ongoing to build highly compact modules by connecting each chip (15 mm x 30 mm) via ball type connections to a flex cable (~50 connections/chip).

Power and electrical connections off-detector are provided at the end of the module.

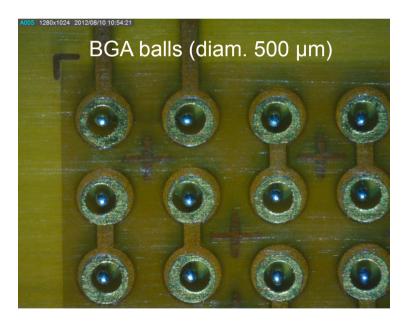


Interconnection studies

Evaluation of different techniques

Several alternative interconnections techniques are under investigation using specially produced test chips and kapton flex cables.

- BGA ball connections (includes reflow in furnace)
- 2. Solder ball connections using laser soldering
- 3. Au-stud bonding (includes curing step at moderate temperature)
- 4. Ultra-thin chip packaging

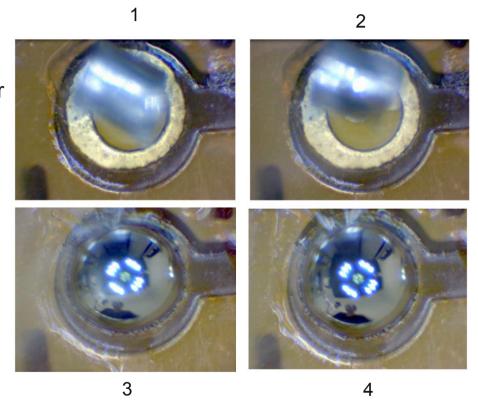




Interconnection studies

Laser soldering

- Local heating of solder balls using a laser
- Advantage: stress only induced locally during few hundred ms
- First trials with kapton chips and cables successfully completed
- Next step: solder tests with silicon test chips connected to a kapton flex cable



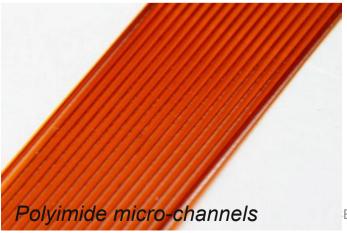


Cooling studies

2 concepts - Layers 1,2,3

Cold plate





Cooling pipes



Prototype modules built Evaluation and simulation work ongoing

Example: polyimide tubes shown in the following slides



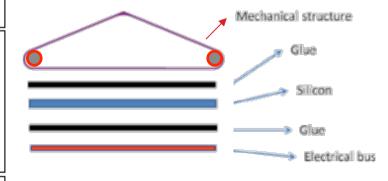
Mechanical structure

Prototype modules

Module prototype equipped with dummy components (27 cm long, inner layers)

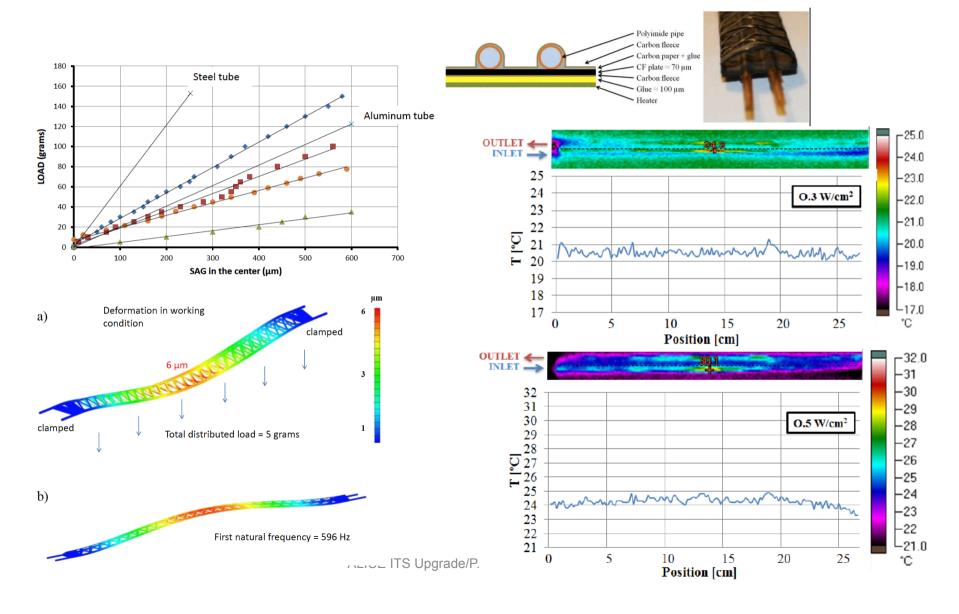


Material	Surface (%)	Tickness (μm)	X ₀ (cm)	X/X ₀ (%)	Contribution to the total X/X ₀ (%)
CFRP filament	100	70	25	0.035	12.6
CFRP mament	100	70	2.3	0.055	12.0
Polyimide Tubes	19	70	28.6	0.005	1.8
Water	19	1450	36.1	0.06	22.8
Glue (CFRP - silicon)	50	100	44.4	0.01	4.4
Silicon	100	50	9.36	0.054	20.7
Glue (silicon - bus)	100	100	44.4	0.022	8.7
Electrical bus	100	-	-	0.075	29.0
Total				≈ 0.26	





Structural and thermal tests







Timeline

2012–2014	R&D
2012	evaluation of technologies & prototypes
2013	selection of technologies, eng. Design, TDR
2014	final design and validation
2015-18	Construction and Installation
2015-16	production, construction and test of detector modules
2017	assembly and pre-commissioning
2018	installation in the cavern



Summary

The ALICE Silicon Tracker Upgrade will allow to address new physics topics like:

- Quark mass dependence of in-medium energy loss
- Thermalization of heavy quarks in the medium

New Tracker composed of 7 silicon layers characterized by:

- Impact parameter resolution improved by factor 3x
- First detecting layer @22 mm from the beam line
- Material budget $x/X_0 \sim 0.3$ % in the first layers
- High tracking efficiency down to low p_t (> 95% for p_t > 200 MeV/c)
- Fast access for maintenance

Detector technology evaluation ongoing - to be installed during LS2



Backup slides



The ALICE upgrade strategy

Upgrade the ALICE readout and online system:

- read out all Pb-Pb interactions at a maximum rate of 50kHz (i.e. L = $6x10^{27}$ cm⁻¹s⁻¹), with a minimum bias trigger
- Perform online data reduction based on reconstruction of clusters and tracks (tracking used only to filter out clusters not associated to reconstructed tracks)



Requirements

Focus of ALICE upgrade on physics probes requiring high statistics: sample 10 nb⁻¹

Online System Requirements

Sample full 50kHz Pb-Pb interaction rate (current limit at ~500Hz, factor 100 increase)

⇒ ~1.1 TByte/s detector readout

However:

- storage bandwidth limited to ~20 GByte/s
- many physics probes have low S/B: classical trigger/event filter approach not efficient



Strategy

Data reduction by (partial) online reconstruction and compression

Store only reconstruction results, discard raw data

- Demonstrated with TPC clustering since Pb-Pb 2011
- Optimized data structures for lossless compression
- Algorithms designed to allow for offline reconstruction passes with improved calibrations
- ⇒ Implies much tighter coupling between online and offline reconstruction software

Why triggering does not work? The open charm case

Estimated signal statistics and trigger rate for minimum-bias Pb-Pb collisions Hadronic Interaction rate of 50 kHz

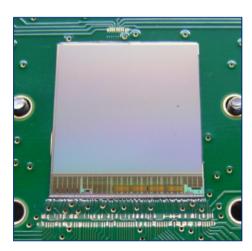
Particle	Eff	S/ev	S/B	B'/ev	trigger	S/nb^{-1}
					rate (Hz)	
D_0	0.02	$1.6 \cdot 10^{-3}$	0.03	0.21	$11 \cdot 10^{3}$	$1.3 \cdot 10^{7}$
$\mathrm{D_{s}^{+}}$	0.01	$4.6 \cdot 10^{-4}$	0.01	0.18	$9 \cdot 10^{3}$	$3.7 \cdot 10^6$
$\Lambda_{ m c}$	0.01	$1.4 \cdot 10^{-4}$	$5 \cdot 10^{-5}$	11	$5 \cdot 10^4$	$1.1 \cdot 10^{6}$
$\Lambda_{\rm c} \ (p_{\rm t} > 2 \ {\rm GeV}/c)$	0.01	$0.8 \cdot 10^{-4}$	0.001	0.33	$1.6 \cdot 10^4$	$0.6 \cdot 10^6$
$(B \to D^0 (\to K^- \pi^+))$	0.02	$0.8 \cdot 10^{-4}$	0.03	$11 \cdot 10^{-3}$	$5 \cdot 10^2$	$0.6 \cdot 10^6$
$B \rightarrow J/\psi(\rightarrow e^+e^-)$	0.1	$1.3 \cdot 10^{-5}$	0.01	$5 \cdot 10^{-3}$	$3 \cdot 10^{2}$	$1 \cdot 10^{5}$
${ m B^+} ightarrow { m J}/\psi { m K^+}$	0.01	$0.5 \cdot 10^{-7}$	0.01	$2 \cdot 10^{-5}$	1	$4 \cdot 10^{2}$
$\mathrm{B}^+ ightarrow \overline{\mathrm{D}}^0 \pi^+$	0.01	$1.9 \cdot 10^{-7}$	0.01	$8 \cdot 10^{-5}$	4	$1.5 \cdot 10^3$
${ m B_s^0} ightarrow { m J}/\psi \phi$	0.01	$1.1 \cdot 10^{-8}$	0.01	$4.4 \cdot 10^{-6}$	$2 \cdot 10^{-1}$	$9 \cdot 10^{1}$
$\Lambda_b(\to\Lambda_c+e^-)$	0.01	$0.7 \cdot 10^{-6}$	0.01	$2.8 \cdot 10^{-4}$	14	$5 \cdot 10^{3}$
$\Lambda_b(\to\Lambda_c+h^-)$	0.01	$0.7 \cdot 10^{-5}$	0.01	$2.8 \cdot 10^{-3}$	$1.4 \cdot 10^2$	$5 \cdot 10^4$

B' is the background in the broad invariant mass range ($\pm 12\sigma$)



Monolithic Pixels (IPHC)

- CMOS sensors with rolling-shutter readout architecture
- MIMOSA series for STAR.
 - Continuous charge collection (mostly by diffusion) inside the pixel
 - Charge collection time ~200 ns
 - Pixel matrix read periodically row by row: column parallel readout with end of column discriminators
 - Integration time = readout period ~100 μs
 - Low power consumption: only one row is powered time: (150-250 mW/cm²)
 - Pixel size 20 μm
 - Total material budget x ~ 0.3% X₀
 - 0.35 μm technology node

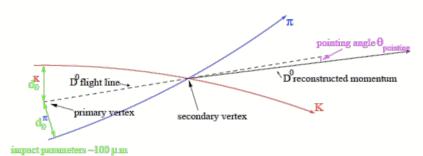


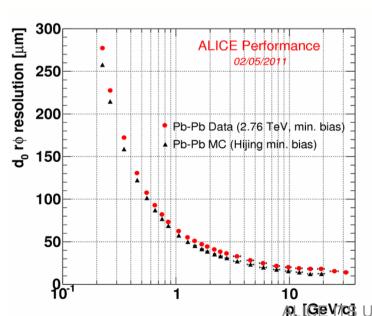
ULTIMATE sensor for STAR HFT

ALICE ITS (current) performance

A Large Ion Collider Experiment

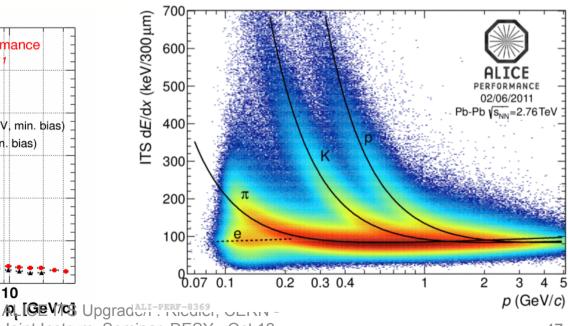
1. The Identification of secondary vertices relies on the impact parameter d_0 (in r ϕ and z)





2. The PID performance (from SPD & SSD)

- PID combined with stand-alone tracking allows to identify charged particles below 100 MeV/c
- p-K (3σ) separation up to 1 GeV/c
- π-K (3σ) separation up to 600 MeV/c
- dE/dx resolution of about 10-15%



Joint Instrum. Seminar, DESY - Oct 12, 2012